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Index

A/D converter, 6
Accumulator, 9
Active inductor
   see Integrated inductor, active, 53
Amplitude noise, 17, 59
Antenna signal, 6
Arithmetic mean distance, 125
Bandpass filter, 67
Barkhausen, 50
Baseband signal, 6
Behavioral model, 208
Bode plot, 30
Bonding pad, 98
Bonding wire inductor, 87, 90, 106
   inductance variation, 95
   parasitics, 98
   series resistance, 103
   substrate loss, 104
Bonding wire VCO, 93, 114
Capacitor bank, 187
Cellular, 2, 4
   hand-off, 2
   roaming, 3-4
Center frequency, 21
Charge pump, 26, 34, 190
   noise, 197, 207
   spurs, 191
Circular inductor, 127
CMOS
   processing technology, 5
Coarse tuning, 187
Crossover frequency, 193, 206

Crystal, 36
   oscillator, 36, 68
D/A converter, 9
Damping factor, 32
DCS-1800, 5, 150, 187
   phase noise, 17
   time slots, 201
Delay line, 117, 152
Dirac, 16
Direct digital frequency synthesis, 11
Direct upconversion, 7
Divide-by-\(N + 1/2\), 166
Divide-by-2, 164, 168
Drain resistance, 111
Dual-modulus prescaler, 168
   conventional, 162
   phase-switching, 164
Eddy currents, 130
Effective capacitance, 71, 75, 110
Effective resistance, 61, 71, 75, 94, 110, 139, 149
Effective signal, 76, 78
Emitter-coupled multivibrator, 38
Enhanced LC-tank, 78, 106
Epi-layer, 100
Etched substrate, 123
Feedback system, 21, 50
Fessenden, Reginald, 2
Finite-element simulation, 91, 96, 104, 127
Fixed network, 1
Forward gain, 22
Fractional-N, 44

245
Frequency divider, 10, 41, 161
Frequency spectrum, 2
Frequency synthesizer, 8
direct, 9
indirect, 10
dual-loop, 12
table-look-up, 8
Frequency tuning, 108, 117, 142, 152
Fringing capacitance, 146
Front-end, 5–6

Geometric mean distance, 125
GSM, 1, 4, 150
Gyrator, 53

Hand-off, 2
Harmonic frequency, 26
Heterodyne, 6–7
Hold-in range, 25
Hollow coil, 132, 136
symmetrical, 145
Homodyne, 6

Inductor, 51, 59
Integrated inductor
active, 53
active
noise, 54
phase noise, 63, 72
bonding wire
see Bonding wire inductor, 55
planar
see Planar inductor, 55
spiral
see Planar inductor, 55
Integration, 6
Interface, 4
Intermediate frequency, 6

Jitter, 19
Junction capacitor, 108, 140

LC-oscillator, 40, 50
phase noise, 57
Linearization, 212
LO
see Local Oscillator, 6
Local oscillator, 6, 8
Lock-in range, 25
Loop filter, 30, 193
dual path, 202
noise, 198, 208

passive, 195
Marconi, Guglielmo, 2
Master/slave flipflop, 164
Microprocessor, 2
Mirror signal, 7
Mixer, 6, 9
Mobile telephone, 2
Modulation, 6

Natural frequency, 32
Negative resistance, 111, 139, 149
bipolar, 112
CMOS, 111
Octagon, 122
Open loop gain, 206
OTA-C oscillator, 41

Parallel resonance, 37
Parasitic resistor, 50
Pattern noise, 46
PD
see Phase Detector, 10
Phase detector, 10, 25
exor, 26
flip-flop, 26
multiplier, 26
phase-frequency detector, 26
Phase error voltage, 21
Phase margin, 193
Phase noise, 16–17, 40, 52, 142, 151, 220
1/f noise, 83, 152, 220
active inductor, 66
crystal, 75
FM-modulation, 81
passive inductor, 62
prescaler, 177
Phase-frequency detector, 26, 190
crossover distortion, 28
dead zone, 28
Phase-locked loop, 10, 20, 189
acquisition, 24
noise, 21
order, 23
settling time, 24
tracking, 23
type, 23
Phase-selection, 165, 173
Phase-switching prescaler, 162, 164
divide-by-2, 164, 168, 178
master/slave, 164
multi-modulus, 167, 177
phase-selection, 165, 173
Pierce oscillator, 37, 73
Planar inductor VCO, 136, 142
Planar inductor, 86, 122
etched, 123
finite-element simulation, 126
guidelines, 135
inductance calculation, 125
model, 134
series resistance, 123, 128
eddy currents, 130
skin effect, 128
substrate loss, 125, 132
symmetrical, 145
PLL
see Phase-Locked Loop, 10
Power, 2
Prescaler, 43, 161
dual-modulus, 43, 162
multi-modulus, 167
phase-switching
see Phase-switching prescaler, 162
Pull-in range, 25

Quadrature, 7
Quality factor, 52, 61, 71

Radio communication, 2
Receiver, 6, 17
heterodyne, 6
homodyne, 6
IF, 6
low-IF, 7
wideband-IF, 7
zero-IF, 6
Reference frequency, 10
Reference, 20, 190
Relaxation oscillator, 38
Ring oscillator, 39
Roaming, 3–4

Schmitt-trigger, 215
Self resonance, 123, 127
Series resonance, 36
Settling time, 201, 222
Sigma-delta modulator, 46
Signal-to-noise ratio, 63
Skin depth, 103
Skin effect, 103, 128
Spectrum analyzer, 114
Spurious frequency, 26, 221
Spurs, 9
Stability, 32
Startup, 51
Steady-state phase error, 23
Substrate loss, 104, 127
Substrate, 100
Switched capacitor, 188
Switching system, 3

Technology, 8
BiCMOS, 8
bipolar, 8
CMOS, 8
discrete, 8
GaAs, 8
Transceiver, 6
Transient phase error, 24
Transistor, 2
Transmitter, 7, 18
heterodyne, 7
homodyne, 7
IF, 7
zero-IF, 7
True phase single clock, 168

VCO
see Voltage-Controlled Oscillator, 10
Voltage-controlled oscillator, 10, 35
crystal, 36
LC, 40
OTA-C, 41
phase noise, 22
relaxation, 38
ring, 39

Wafer type, 100, 125